

Initial Information Data Sheet

Inventor Information

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Correspondence Information

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Application Information

Title Line One: NONVOLATILE SEMICONDUCTOR MEMORY DEVICE
Title Line Two: AND METHOD OF ERASING THE SAME
Total Drawing Sheets: 18
Formal Drawings?: Yes
Application Type: Utility
Docket Number: 204552022200

Representative Information

Representative Customer Number: 25227

Continuity Information

This application is a:
> Application One:
Filing Date:

Prior Foreign Application

Foreign Application One: 2001-013029
Filing Date: January 22, 2001
Country: Japan
Priority Claimed: Yes

2001-013029